



2.0A GLASS PASSIVATED BRIDGE RECTIFIER

Features and Benefits

- Glass Passivated Die Construction
- High Case Dielectric Strength of 1,500 V_{RMS}
- Low Reverse Leakage Current
- Surge Overload Rating to 65A Peak
- Ideal for Printed Circuit Board Applications
- UL Listed Under Recognized Component Index, File Number F94661
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)

Mechanical Data

Case: KBP

- Case Material: Molded Plastic. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Tin Plated Leads. Solderable per MIL-STD-202, Method 208 (2)\$
- Polarity: Marked on BodyMarking: Type Number
- Weight: 1.52 grams (Approximate)

KBP



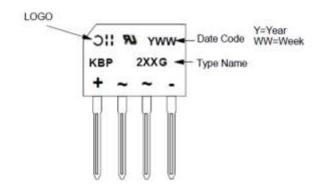
Ordering Information (Note 3)

Part Number	Compliance	Case	Packaging
KBP2005G	Commercial	KBP	35 Pieces per Tube
KBP201G	Commercial	KBP	35 Pieces per Tube
KBP202G	Commercial	KBP	35 Pieces per Tube
KBP204G	Commercial	KBP	35 Pieces per Tube
KBP206G	Commercial	KBP	35 Pieces per Tube
KBP208G	Commercial	KBP	35 Pieces per Tube
KBP210G	Commercial	KBP	35 Pieces per Tube

Notes:

- 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
- See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information





Maximum Ratings (@ $T_A = +25^{\circ}C$, unless otherwise specified.)

Single phase, half wave, 60Hz, resistive or inductive load.

For capacitance load, derate current by 20%.

Characteristic	Symbol	KBP2005G	KBP201G	KBP202G	KBP204G	KBP206G	KBP208G	KBP210G	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _{RM}	50	100	200	400	600	800	1,000	V
RMS Reverse Voltage	V _{R(RMS)}	35	70	140	280	420	560	700	V
Average Rectified Output Current @T _C = +105°C	lo				2.0				Α
Non-Repetitive Peak Forward Surge Current 8.3ms Single Half Sine-Wave Superimposed on Rated Load	I _{FSM}	65					Α		
I^2 t Rating for Fusing (3ms \leq t \leq 8.3ms)	l ² t				17.5				A ² s

Thermal Characteristics

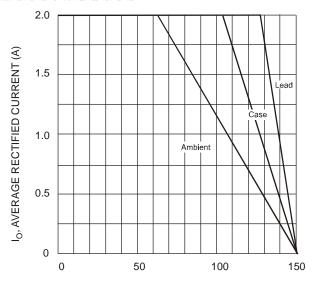
Characteristic	Symbol	Value	Unit
Typical Thermal Resistance, Junction to Case (Note 4)	R _{θJC}	14	°C/W
Typical Thermal Resistance, Junction to Lead	R _{θJL}	18	°C/W
Typical Thermal Resistance, Junction to Ambient	ReJL	40	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-65 to +150	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min		Тур	Max	Unit	Test Condition		
Reverse Breakdown Voltage (Note 5)	V _{(BR)R}	KBP210G KBP208G KBP206G KBP204G KBP202G KBP201G KBP2005G	1,000 800 600 400 200 100 50	ı	ı	V	I _R = 5μA		
Forward Voltage Drop per Element	V _F	_		1	1.1	V	I _F = 2A, T _J = +25°C		
Leakage Current (Note 5)	I _R	_		_			5 500	μΑ	$V_R = V_{RRM}, T_C = +25$ °C $V_R = V_{RRM}, T_C = +125$ °C
Total Capacitance per Element	Ст	_		25	_	pF	$V_R = 4.0V_{DC}$, $f = 1MHz$		

4. Thermal resistance from junction to case per element. Device mounted on 75mm x 75mm x 1.6mm Cu Plate Heatsink. 5. Short duration pulse test used to minimize self-heating effect. Notes:





T, TEMPERATURE (°C)
Fig. 1 Forward Current Derating Curve

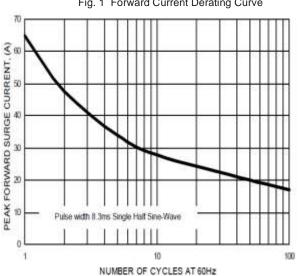
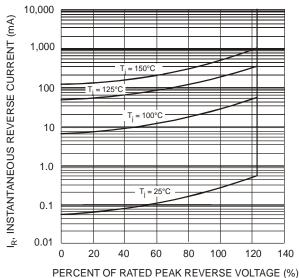
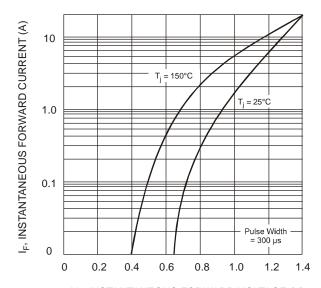


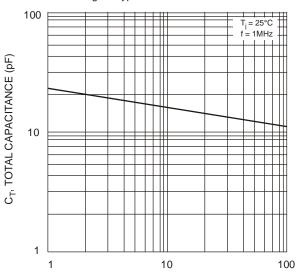
Fig. 3 Maximum Non-Repetitive Surge Current



PERCENT OF RATED PEAK REVERSE VOLTAGE (% Fig. 5 Typical Reverse Characteristics



V_F, INSTANTANEOUS FORWARD VOLTAGE (V) Fig. 2 Typical Forward Characteristics



 $\rm V_{R}$, REVERSE VOLTAGE (V) Fig. 4 Typical Total Capacitance, Per Element

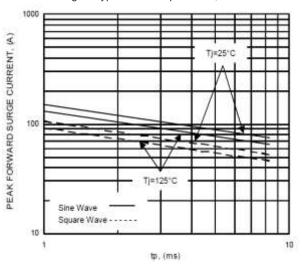
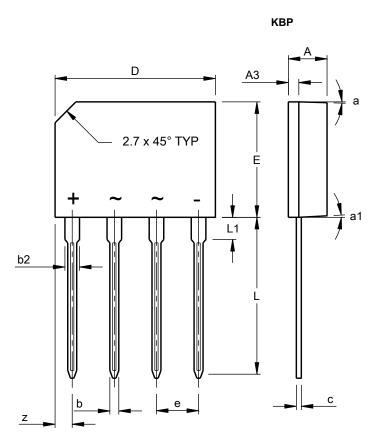


Fig. 6 Non-Repetitive Surge Current



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.



КВР							
Dim	Min	Тур					
Α	3.35	3.65	-				
A3	0.80	1.10	-				
b	0.76	0.86	-				
b2	1.22	1.42	-				
С	0.35	0.55	-				
D	14.25	14.75	-				
Е	10.20	10.60	-				
е	3.56	4.06	-				
L	14.25	14.73	-				
L1	1.80	2.20	-				
Z	1.40	1.70	-				
а	-	-	3°				
a1	-	-	2°				
All Dimensions in mm							



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